NSN 5961-01-143-3242

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-143-3242 **Inclosure Material:** Metal **Overall Length:** 0.123 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse gate to source breakdown voltage **Current Rating Per Characteristic:** 0.01 milliamperes forward current, average peak **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 600.0 degrees celsius ambient air **Terminal Type And Quantity:** 1 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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